		OPMATION DIOGRAPHIE			ATTY DOCKET NO. 16877			SERIAL NO.  unassigned		
•	HAL	ORMATION DISCLOSUR (Use several sheets if nece	E CITATION ssary)		TEIICHIRO NISHIZ			<del></del>		
					FILING herewith			GROUP unassigned		
•			Ü	J.S. PATENT	DOCUMENTS		e in	issigned		
EXAMINER		DOCUMENT NUMBER	DATE	NAME		CLASS	SUBCLASS	FILING DATE	FILING DATE	
LP		6,399,441	6/4/2002	Ogura				IF APPROPRIATE		
		6,388,293	5/14/02	Ogura, et al.		†			<del>-,- <u>-</u></del> -	
		6,011,725	1/4/00	Eitan	*					
		6,256,231	7/3/01	Lavi, et al.		/	<del> </del>			
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			FORE	EIGN PATENT	DOCUMENTS					
		DOCUMENT NUMBER	DATE		COUNTRY	CLASS	SUBCLASS	TRANSLATION		
LP		2001-230332	8/24/01	Japan				YES NO		
	2002-26149		1/25/02	Japan						
		2001-357681	12/26/01	Japan						
		2001-512290	8/21/01	Japan				1		
V		2001-156189	6/8/01	Japan					7	
		OTHER DOCUME	NTS (Includin	ng Author, T	itle, Date, Pertinent P	Pages, Etc.)	· · · · · · · ·		٦	
LP		A Novel 2-bit/cell MON( Injection by Hideto Tom	OS Memory Devi iye et al., 2002 S	ice with a Wr ymposium on	apped-Control-Gate Str VLSI Technology Diges	ucture that Ap t of a Technica	plies Source-S il papers, pp 2	ide Hot Electroi 06-207.	,	
			•					<del></del>		
CAMINER		Long P	lang	D	ATE CONSIDERED	3/21	low		1	
XAMINER:	: Initial	if reference considered, whether	or not citation is	in conformanc	e with MPEP 609; Draw lin	ne through citati	on if not in con	formance and not		

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